NSN 5962-01-501-4447

Digital Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.6 watts
Operating Tempurature Range:
55.0/+85.0 degrees celsius
Storage Tempurature Range:
65.0/+125.0 degrees celsius
End Application:
PATR-IO-TMI-SSIL
Features Provided:
Monolithic and electrostatic sensitive
nclosure Configuration:
Leaded chip carrier
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Design Function And Quantity:
1 central processor unit
Terminal Surface Treatment:
Solder
Product Name:
Missile command specification microcircuit, digital, cmos, application specific integrated circuit (asic) expanded weapons control computer
(ewcc) fetch chip
Voltage Rating And Type Per Characteristic:
0.5 volts input and 7.0 volts input
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
172 flat leads
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Filg:
A458a0